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(54) **SiC SINGLE CRYSTAL AND METHOD FOR GROWING THE SAME**

SIC-EINKRISTALL UND HERSTELLUNGSVERFAHREN DAFÜR
MONOCRISTAL EN SIC ET SON PROCEDE DE CROISSANCE

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- **Z.Y. CHEN ET AL.:** 'Specular surface morphology of 4H-SiC epilayers grown on (1120) face' JPN. J. APPL. PHYS. vol. 38, no. 12A, PART 2, 01 December 1999, pages L1375 - L1378, XP002934217
- Remarks:
The file contains technical information submitted after the application was filed and not included in this specification

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